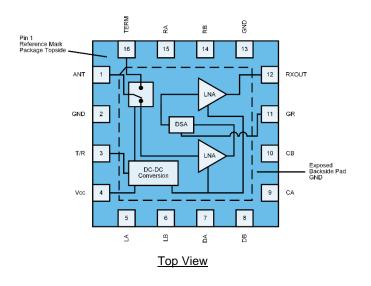
#### **Product Overview**

The Qorvo® QPC9314 is a highly integrated front-end module targeted for TDD macro or picocell base stations. The LNA switch module integrates RF functional blocks such as a pin-diode based high power switch capable of handling up to 52 W with an LTE signal (8 dB PAR) along with two LNA stages, and a 1-bit DSA to provide a high and low gain mode. Further integration is also implemented where the pin diode driver and dc-dc converter circuits are implemented inside the module to enable only the need for an external 5 V power supply. The control voltage for the switch and gain control. mode is with 3.3 V logic.

The QPC9314 can be utilized across the 2.3-2.7 GHz range to provide 1.2 dB noise figure for operation in the receive mode and 0.5 dB insertion loss in the transmit mode. The LNAs utilize Qorvo's high performance E-pHEMT process while the switch allows for power levels up to 330 W peak power to be routed to an external load termination.

The QPC9314 is packaged in a RoHS-compliant, compact 8x8 mm surface-mount leadless package. The switch LNA module is targeted for wireless infrastructure applications configured for TDD-based architectures.

#### **Functional Block Diagram**



#### QPC9314 High Power Switch LNA Module



16 Pin 8 mm x 8 mm leadless SMT Package

#### **Key Features**

- 2.3-2.7 GHz frequency range
- Integrates a high power switch, two LNA stages, a 1-bit DSA, pin diode driver circuits, and dc converter
- Ideal for TDD systems with an isolator
- Only requires a 5 V supply with 3.3 V logic Ctrl.
- Max RF Input power: 52 W Pavg (8 dB PAR)
- 33 or 24 dB gain (Rx high and Rx low gain mode)
- 1.2 dB noise figure
- +33 dBm OIP3 (Rx mode)
- 0.65 dB Insertion Loss (Tx mode)
- Compact package size, 8x8 mm

#### **Applications**

- Wireless Infrastructure
- Macro or picocell base stations
- TDD-based architectures

#### **Ordering Information**

Part No.	Description
QPC9314TR13	2500 pcs on a 13" reel
QPC9314SR	100 pcs on a 7" reel
QPC9314EVB	Evaluation board

## QOLAD

#### QPC9314 **High Power Switch LNA Module**

#### Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-50 to 150 °C
Max Operating Temperature	+115 °C
Vcc	+6 V
RF at ANT (Tx Mode) <sup>(1)</sup>	+47.2 dBm
RF at ANT (Tx Mode) (2)	+44.2 dBm
RF at ANT (Tx Mode) (3)	+46.0 dBm
RF at ANT (Rx Mode) (2)	+20 dBm

Notes:

10s, 8 dB PAR, 88% duty cycle, +100°C, 1CH LTE 1.

2. Indefinitely, 8 dB PAR, 88% duty cycle, +100°C, 1CH LTE

20s, 8 dB PAR, 80% duty cycle, +100°C, 1CH LTE 3.

Operation of this device outside the parameter ranges

given above may cause permanent damage.

#### **Electrical Specifications**

Test conditions unless otherwise noted:  $V_{CC}$  = +5.0 V, Temp. = +25 °C, 50  $\Omega$  system

#### Parameter Conditions Min Max Units Typ **Operational Frequency Range** 2300 2700 MHz 2595 MHz **Test Frequency** Rx mode, high gain mode 31 33 dB Gain 22 24 Rx mode, low gain mode dB Gain Flatness Rx mode, 2.3-2.4 GHz or 2.5-2.7 GHz 0.4 dB Rx mode, high gain mode 1.2 1.4 dB Noise Figure 1.7 1.5 dB Rx mode, low gain mode Rx mode, high gain mode -3.0 1.0 dBm Input IP3 Rx mode, low gain mode 8 dBm -10 dBm Rx mode, high gain mode Input P1dB Rx mode, low gain mode -4 dBm 20 Input Return Loss Rx mode, ANT port 16 dB **Output Return Loss** Rx mode, high gain mode, Rx Out port 13 dB 55 **Reverse Isolation** Rx mode dB Tx mode 0.5 1.0 dB Insertion Loss Input P0.1dB Tx mode 47.6 dBm Tx mode, ANT and TERM ports dB **Return Loss** 15 Rx mode 250 300 mΑ **Operating Current** Tx mode 140 180 mΑ

**Thermal Resistance** 

Notes:

Switching Time (ANT to Rx Out)

In Band Spurious Emission (5)

Out of Band Emissions (7)

5. Pin is a CW signal swept from 2.3 to 2.7GHz. Spec refers to any spurious mixing product that occurs from 2.3 to 2.7GHz.

50% of CTL to 10% / 90% of RF Output

Rx Mode at Rx out with Pin = -49dBm <sup>(6)</sup>

Rx Mode at Rx out from DC to 12275MHz

Recommend to follow Qorvo EVB layout for lowest spur level any deviation can increase spur level. 6.

7 Measure Pout with IBW = 4.5Mhz over frequency range with no input power applied.

Rx mode

Tx mode

uS

dBc

dBm

°C/W

°C/W

#### **Recommended Operating Conditions**

Parameter	Min	Тур	Мах	Units
Vcc	+4.75	+5	+5.25	V
T/R Mode Low Voltage	0		0.8	V
T/R Mode High Voltage	2.0		3.6	V
T <sub>CASE</sub>	-40		+105	°C
Tj for >10 <sup>6</sup> hours MTTF <sup>(4)</sup>			+190	°C

Notes:

4. For Rx Mode operation

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

1.1

-85

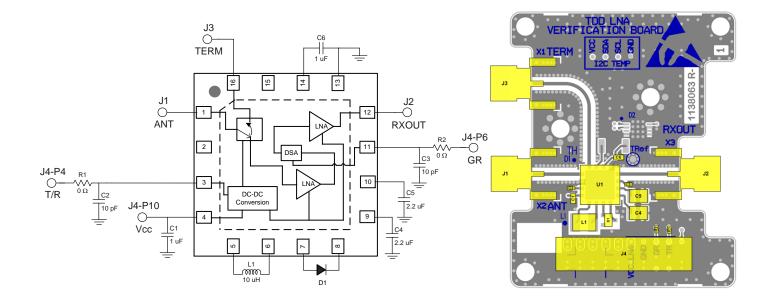
-59

30

22

#### QPC9314 High Power Switch LNA Module

#### **Application Circuit Schematic and Layout**



#### **Bill of Material**

Ref Des	s Value Description		Manuf.	Part Number
n/a	n/a	Printed Circuit Board		
U1	n/a	High Power Switch LNA Module	Qorvo	QPC9314
R1, R2	0 Ω	Resistor, Chip, 0402, 5%	Various	
C1, C6	1 uF	Capacitor, Chip, 0603, 20%, X7R	Various	
C2, C3	10 pF	Capacitor, Chip, 0402, NPO/COG, 5%	Various	
C4, C5	2.2 uF	Capacitor, Chip, 1210, 100 V, 10%, X7R	Various	
D1	n/a	Diode 200 V 200 mA SOT23	Various	
L1	10 uH	Inductor, Power, 10 uH, 20%, 0.84 A	TDK	VLCF4020T-100MR85

#### Logic Table

Parameter	High	Low
T/R	Rx Mode	Tx Mode
GR	Rx Low Gain	Rx High Gain

#### **Typical Performance – Rx Mode (High Gain)**

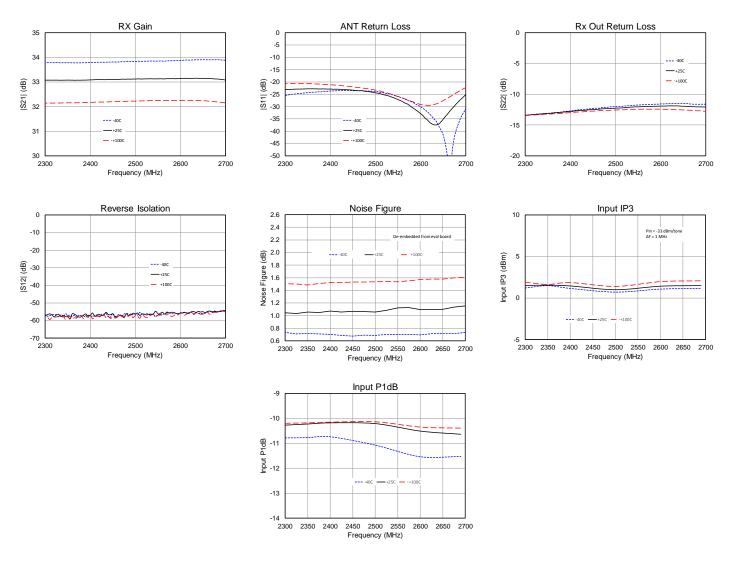
Parameter	Conditions <sup>(1)</sup>	Typical Value			Units	
Frequency		2300	2500	2700	MHz	
Gain		33	33	33	dB	
Input IP3	Pin = -33 dBm/tone, Δf=1 MHz	+1.5	+1.0	+1.5	dBm	
Input P1dB		-10.2	-10.2	-10.7	dBm	
Noise Figure	De-embedded from Evaluation board PCB	1.1	1.1	1.2	dB	
Return Loss	ANT port	20	20	20	dB	
Return Loss	Rx Out port	13	12	12	dB	
Reverse Isolation	Rx Out to ANT port	56	55	54	dB	

Notes:

1. Test conditions unless otherwise noted:  $V_{CC}$  = +5.0 V, T/R = 3 V, GR = 0 V, Temp. = +25 °C

### Performance Plots – Rx Mode (High Gain)

Test conditions unless otherwise noted: V<sub>CC</sub> = +5.0 V, T/R = 3 V, GR = 0 V; Temp.= +25 °C



#### QPC9314 High Power Switch LNA Module

#### **Typical Performance – Rx Mode (Low Gain)**

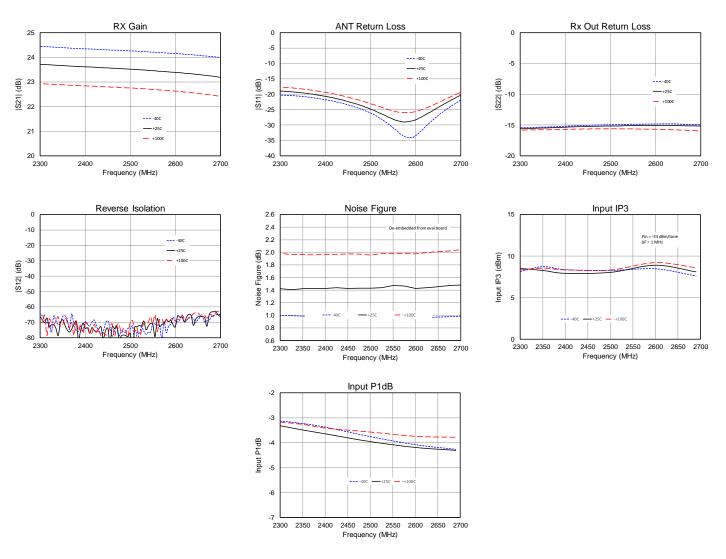
Parameter	Conditions <sup>(1)</sup>	Typical Value			Units
Frequency		2300	2500	2700	MHz
Gain		23.7	23.5	23.2	dB
Input IP3	Pin = -33 dBm/tone, Δf=1 MHz	+7.8	+7.7	+7.7	dBm
Input P1dB		-3.3	-4.0	-4.3	dBm
Noise Figure	De-embedded from Evaluation board PCB	1.4	1.4	1.5	dB
Return Loss	ANT port	19	20	20	dB
Return Loss	Rx Out port	15	15	15	dB
Reverse Isolation	Rx Out to ANT port	65	70	62	dB

Notes:

1. Test conditions unless otherwise noted:  $V_{CC}$  = +5.0 V, T/R = 3 V, GR = 3 V, Temp. = +25 °C

#### Performance Plots – Rx Mode (Low Gain)

Test conditions unless otherwise noted: V<sub>CC</sub> = +5.0 V, T/R = 3 V, GR = 3 V; Temp.= +25 °C



#### **Typical Performance – Tx Mode**

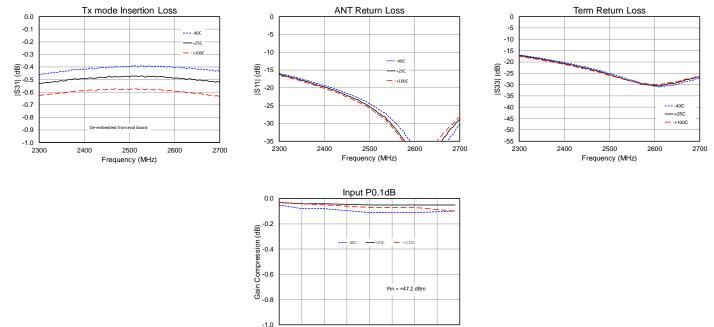
Parameter	Conditions <sup>(1)</sup> Typical Value			ie	Units
Frequency		2300	2500	2700	MHz
Insertion Loss	De-embedded from Evaluation board PCB	0.5	0.5	0.5	dB
Input Compression	Pin = +47.2 dBm	0.05	0.07	0.07	dB
Return Loss	ANT port	16	20	20	dB
Return Loss	TERM port	17	20	20	dB

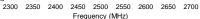
Notes:

1. Test conditions unless otherwise noted:  $V_{CC}$  = +5.0 V, T/R = 0 V, GR = 0 V, Temp. = +25 °C

#### **Performance Plots – Tx Mode**

Test conditions unless otherwise noted: V<sub>CC</sub> = +5.0 V, T/R = 0 V, GR = 0 V; Temp.= +25 °C. Evaluation board PCB loss = 0.3dB.



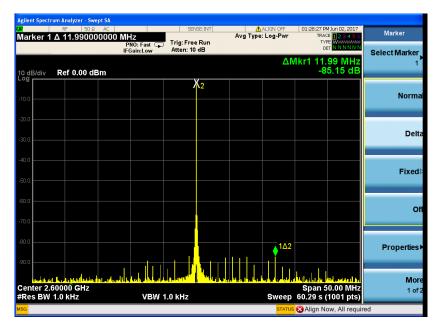


#### **Application Circuit for Reduced Spurious**

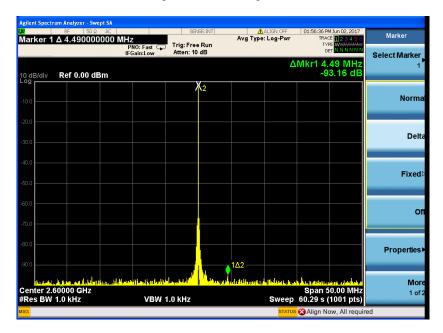
This section describes an alternative way to route the DC-DC converter signals for further improvement of in-band spurious emissions.

#### **Spurious Performance – Modified PCB**

Test conditions unless otherwise noted: V<sub>CC</sub> = +5.0 V, T/R = 0 V, RFin = -35dBm CW; Temp.= +25 °C



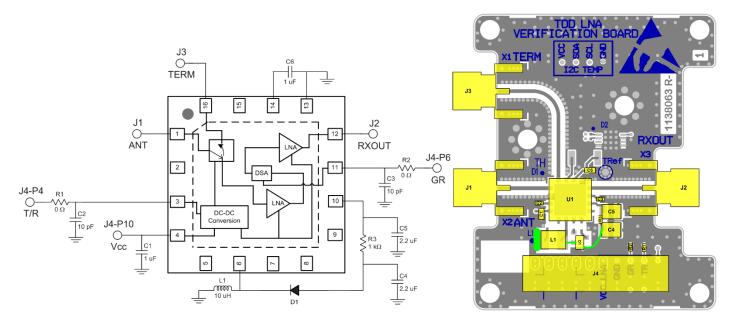
#### **Original PCB Configuration**



Modified PCB Configuration

#### QPC9314 High Power Switch LNA Module

#### **Application Circuit Schematic and Layout – Modified PCB**



Note:

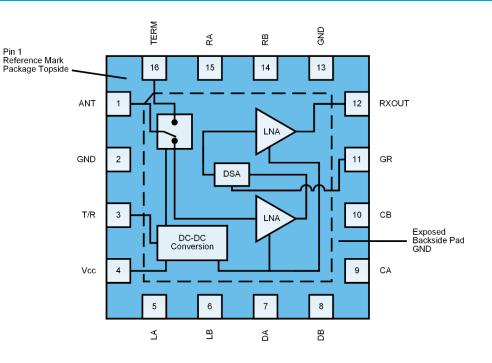
R3 is the only additional component. All other parts are same as unmodified Evaluation Board

#### **Bill of Material – Modified PCB**

Ref Des	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board		
U1	n/a	High Power Switch LNA Module	Qorvo	QPB9325
R1, R2	0 Ω	Resistor, Chip, 0402, 5%	Various	
C1, C6	1 uF	Capacitor, Chip, 0603, 20%, X7R	Various	
C2, C3	10 pF	Capacitor, Chip, 0402, NPO/COG, 5%	Various	
C4, C5	2.2 uF	Capacitor, Chip, 1210, 100 V, 10%, X7R	Various	
D1	n/a	Diode 200 V 200 mA SOT23	Various	
L1	10 uH	Inductor, Power, 10 uH, 20%, 0.84 A	TDK	VLCF4020T-100MR85
R3	1 kΩ	Resistor, Chip, 0402, 5%	Various	

#### QPC9314 High Power Switch LNA Module

#### **Pin Configuration and Description**

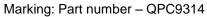


#### Top View

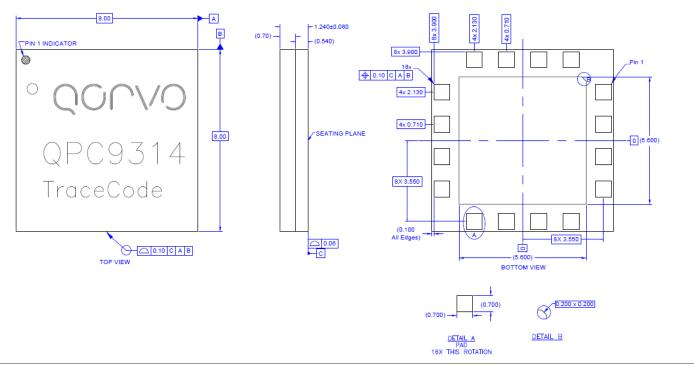
Pin No.	Label	Description
1	ANT	RF antenna input/output port 50 ohms.
2, 13, 14, 15	NC	No Connection.
3	T/R	Switch Control, Tx mode Low state, Rx mode High state.
4	Vcc	DC Power Supply Voltage.
5	LA	External inductor connection for internal power supply.
6	LB	External inductor connection for internal power supply.
7	DA	External diode anode connection for internal power supply.
8	DB	External diode cathode connection for internal power supply.
9	CA	External bypass capacitor connection.
10	СВ	External bypass capacitor connection.
11	GR	Rx mode Gain control, High = Low gain mode, Low = High gain mode.
12	Rx OUT	RF LNA output port 50 ohms.
16	TERM	RF termination port 50 ohms.
Backside Pad	e Pad GND Ground connection. The back side of the package should be connected to ground plan though as short of a connection as possible. PCB via holes un device are required.	

#### QPC9314 High Power Switch LNA Module

#### **Package Marking and Dimensions**



Trace Code – Assigned by assembly sub-contractor



Notes:

- 1. All dimensions are in microns. Angles are in degrees.
- 2. Dimension and tolerance formats conform to ASME Y14.4M-1994.
- 3. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.



#### QPC9314 High Power Switch LNA Module

#### Handling Precautions

Parameter	Rating	Standard	
ESD-Human Body Model (HBM)	Class 1C	ESDA / JEDEC JS-001-2012	Caution!
ESD-Charged Device Model (CDM)	Class C3	JEDEC JESD22-C101F	ESD-Sensitive Device
MSL-Moisture Sensitivity Level	Level 3	IPC/JEDEC J-STD-020	

#### **Solderability**

Compatible with both lead-free (260°C max. reflow temp.) and tin/lead (245°C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: Electrolytic plated Au over Ni

#### **RoHS Compliance**

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS Compliance requirements.
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>0<sub>2</sub>) Free
- PFOS Free
- SVHC Free

#### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: <u>www.qorvo.com</u>

Tel: 1-844-890-8163

Email: customer.support@gorvo.com

For technical questions and application information:

Email: appsupport@qorvo.com

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